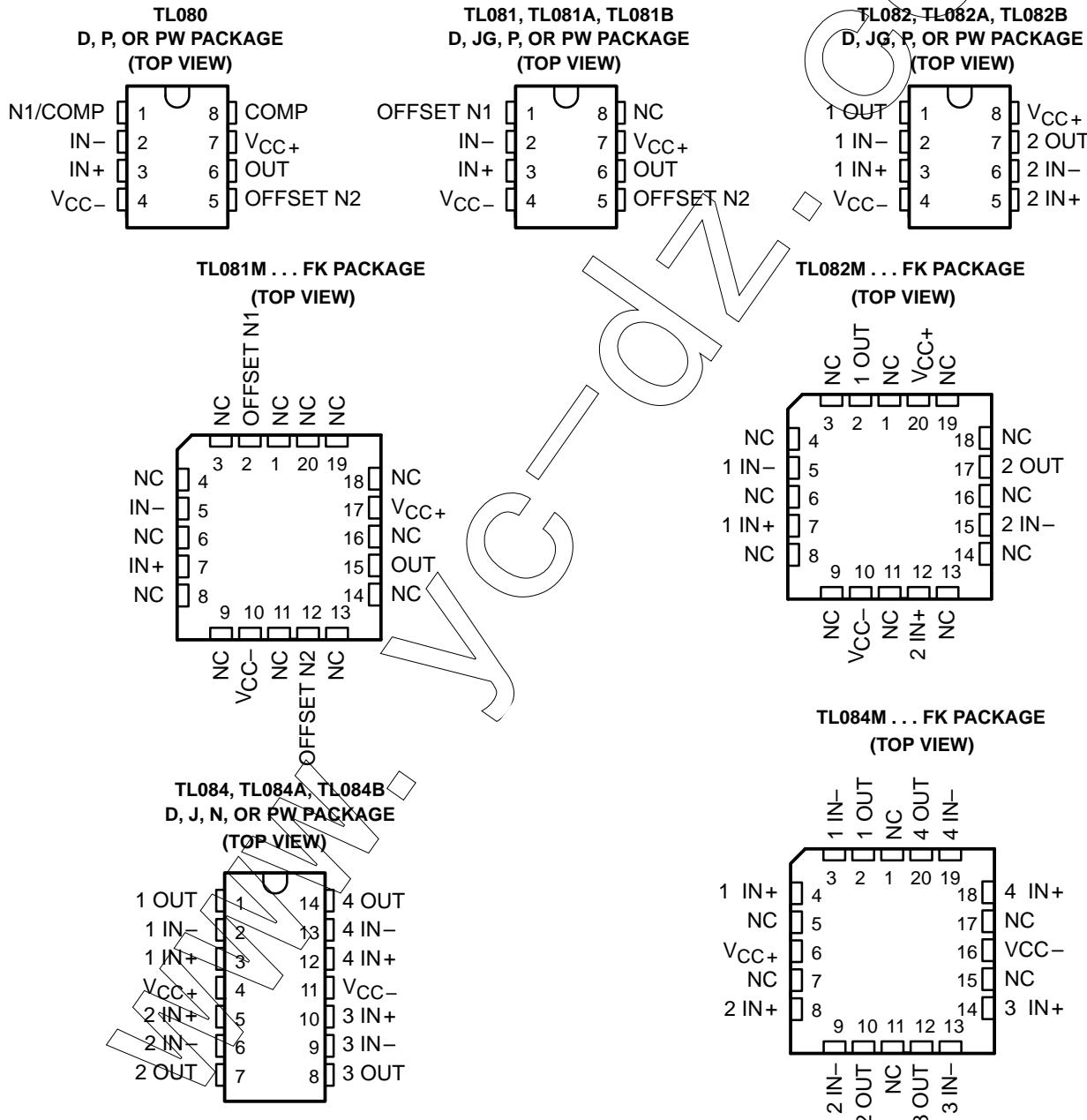


**TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A  
TL081B, TL082B, TL084B, TL082Y, TL084Y  
JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

**24 DEVICES COVER COMMERCIAL, INDUSTRIAL, AND MILITARY TEMPERATURE RANGES**

- Low-Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Output Short-Circuit Protection
- Low Total Harmonic Distortion . . . 0.003% Typ
- High Input Impedance . . . JFET-Input Stage
- Internal Frequency Compensation (Except TL080, TL080A)
- Latch-Up-Free Operation
- High Slew Rate . . . 13 V/ $\mu$ s Typ
- Common-Mode Input Voltage Range Includes  $V_{CC+}$



NC—No internal connection

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
INSTRUMENTS**

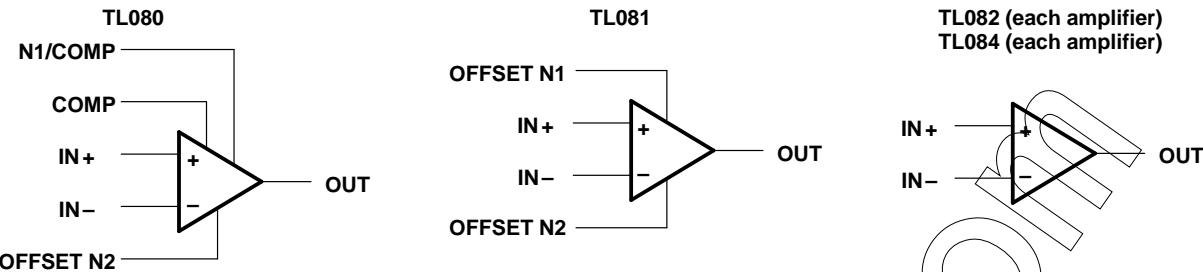
POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS  
77251-1443

Copyright © 1992, Texas Instruments Incorporated  
On products compliant to MIL-STD-883, Class B, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

**TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A  
TL081B, TL082B, TL084B, TL082Y, TL084Y  
JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

**symbols**



**description**

The TL08\_ JFET-input operational amplifier family is designed to offer a wider selection than any previously developed operational amplifier family. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit. The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient. Offset adjustment and external compensation options are available within the TL08\_ family.

Device types with a C suffix are characterized for operation from 0°C to 70°C, those with an I suffix are characterized for operation from -40°C to 85°C, and those with an M suffix are characterized for operation over the full military temperature range of -55°C to 125°C.

**AVAILABLE OPTIONS**

TA	V <sub>IO</sub> MAX at 25°C	PACKAGE								CHIP FORM (Y)
		SMALL OUTLINE (D008)	SMALL OUTLINE (D014)	CHIP CARRIER (FK)	CERAMIC DIP (J)	CERAMIC DIP (JG)	PLASTIC DIP (N)	PLASTIC DIP (P)	TSSOP (PW)	
0°C to 70°C	15 mV 15 mV 6 mV 3 mV	TL080CD TL081CD TL081ACD TL081BCD	—	—	—	—	—	TL080CP TL081CP TL081ACP TL081BCP	TL080CPW TL081CPW	—
	15 mV 6 mV 3 mV	TL082CD TL082ACD TL082BCD	—	—	—	—	—	TL082CP TL082ACP TL082BCP	TL082CPW	TL082Y
	15 mV 6 mV 3 mV	—	TL084CD TL084ACD TL084BCD	—	—	—	TL084CN TL084ACN TL084BCN	—	TL084CPW	TL084Y
-40°C to 85°C	6 mV 6 mV 6 mV	TL081ID TL082ID TL084ID	TL084ID	—	—	—	TL084IN	TL081IP TL082IP	—	—
-55°C to 125°C	6 mV 6 mV 9 mV	—	TL081MFK TL082MFK TL084MFK	TL084MJ	TL081MJG TL082MJG	—	—	—	—	—

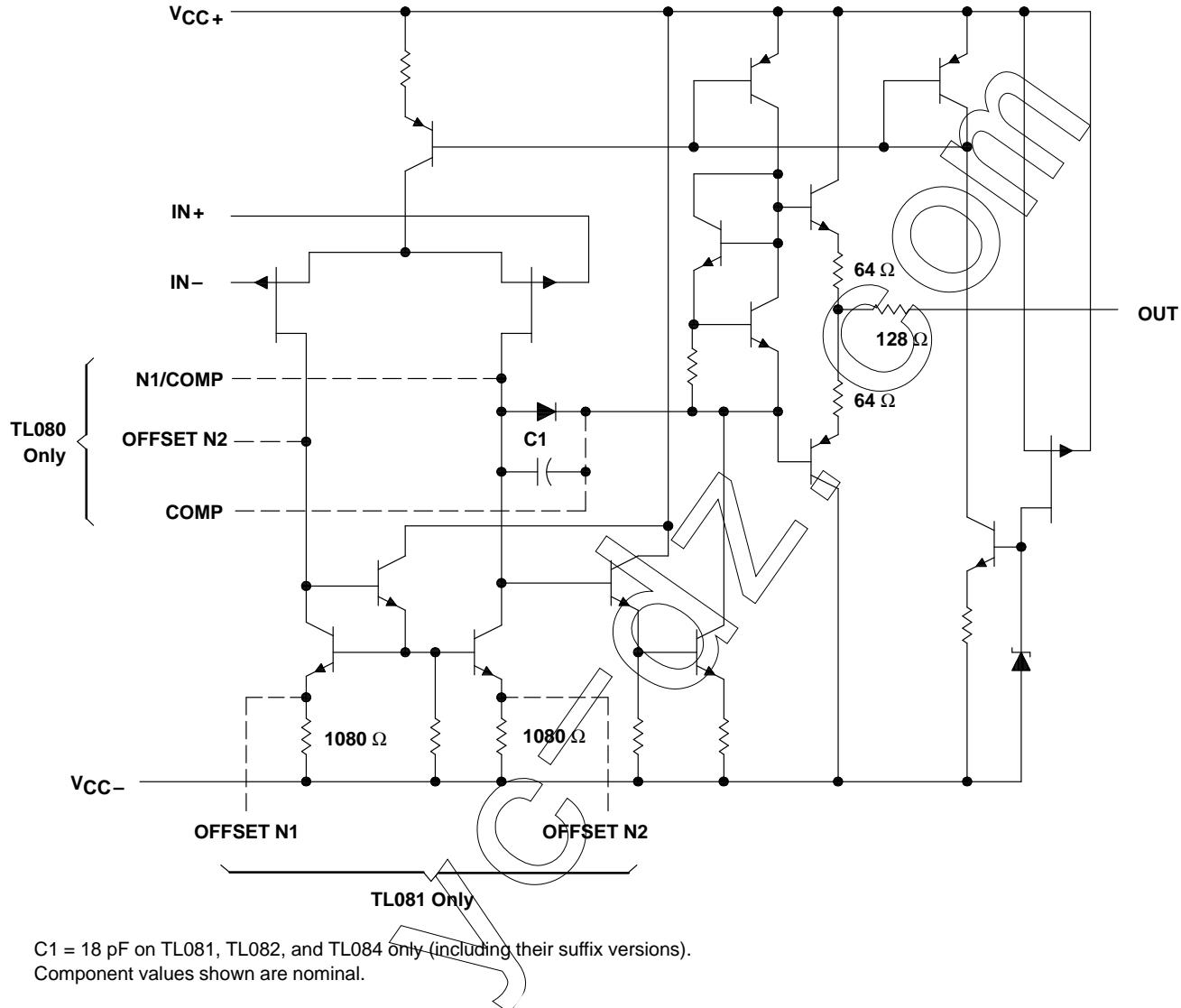
The D package is available taped and reeled. Add R suffix to device type, (e.g., TL080CDR).

**TEXAS  
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS  
77251-1443

**TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A  
JFET-INPUT OPERATIONAL AMPLIFIERS**  
SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

schematic (each amplifier)



WWW.

**TEXAS  
INSTRUMENTS**

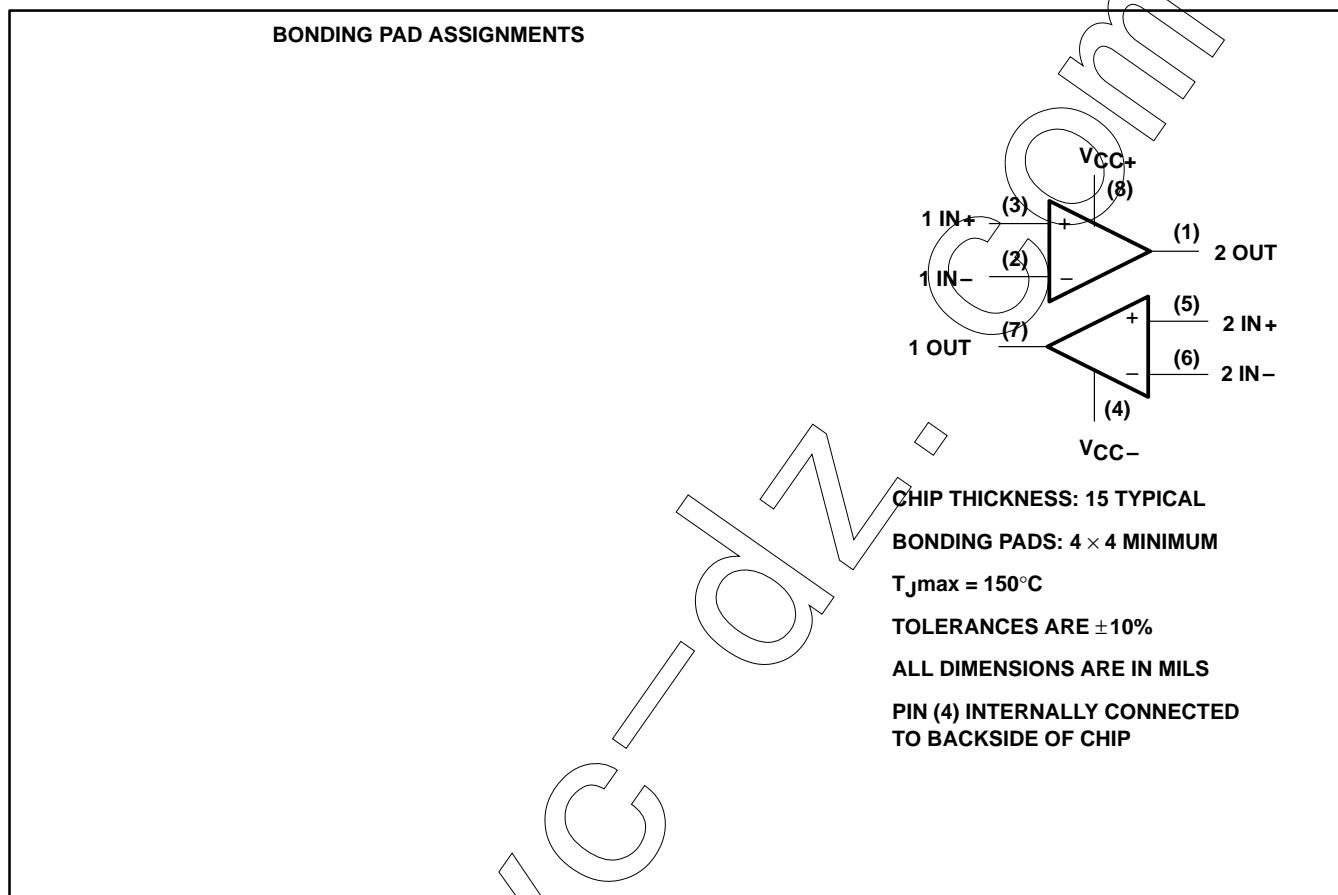
POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS  
77251-1443

# TL082Y JFET-INPUT DUAL OPERATIONAL AMPLIFIER

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

## chip information

These chips, when properly assembled, display characteristics similar to the TL082. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



TEXAS  
INSTRUMENTS

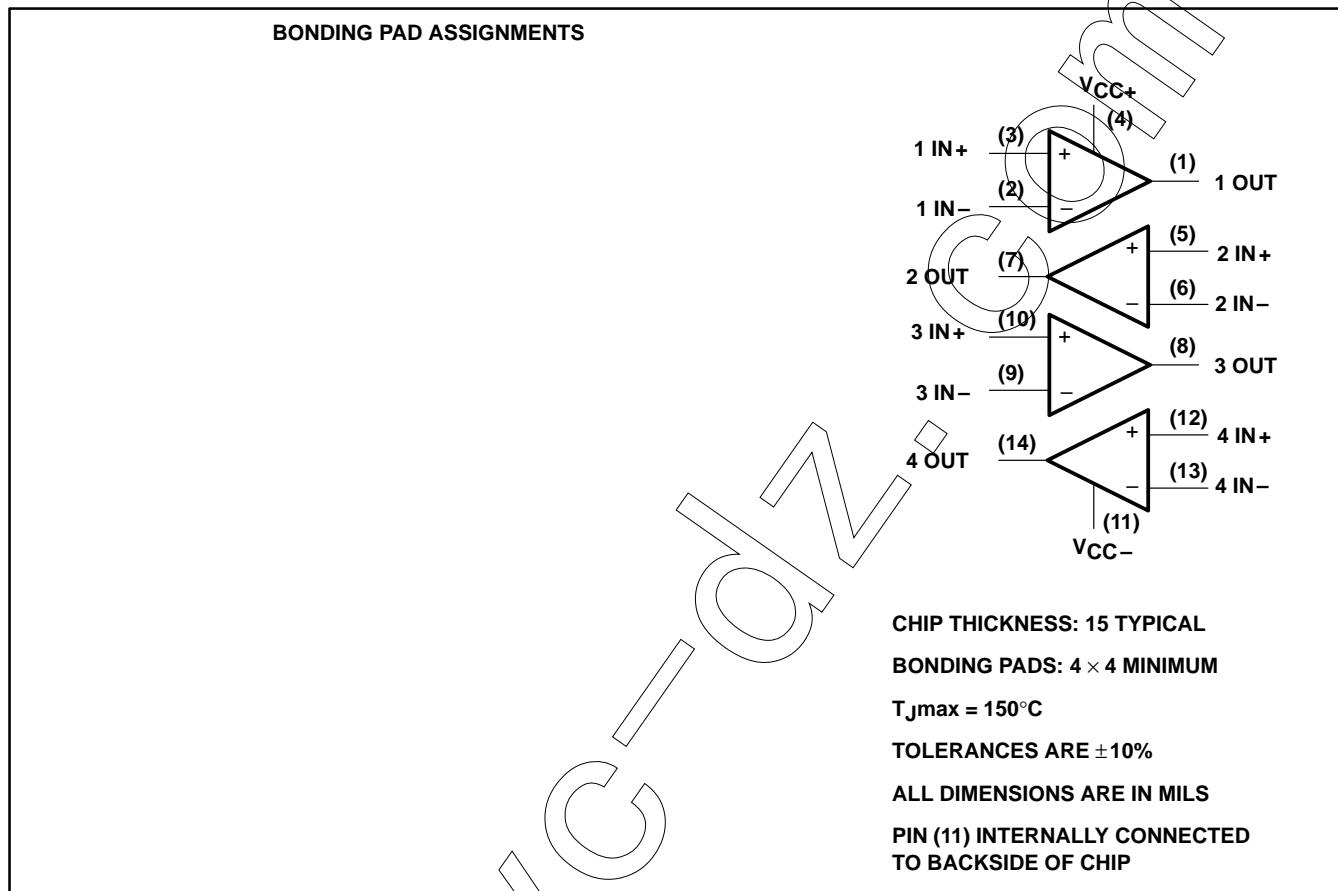
POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS  
77251-1443

TL084Y  
JFET-INPUT QUAD OPERATIONAL AMPLIFIER

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

chip information

These chips, when properly assembled, display characteristics similar to the TL084. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



TEXAS  
INSTRUMENTS

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS  
77251-1443

**TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A**

**TL081B, TL082B, TL084B**

**JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

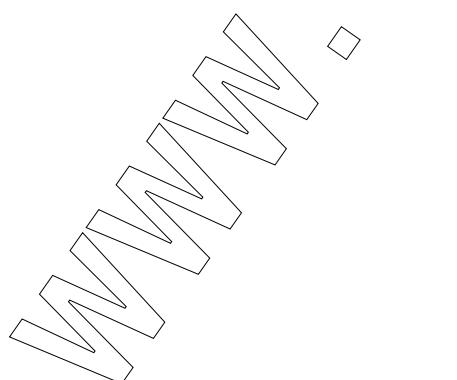
**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)**

	<b>TL08_C TL08_AC TL08_BC</b>	<b>TL08_I</b>	<b>TL08_M</b>	<b>UNIT</b>
Supply voltage, $V_{CC+}$ (see Note 1)	18	18	18	V
Supply voltage $V_{CC-}$ (see Note 1)	-18	-18	-18	V
Differential input voltage (see Note 2)	$\pm 30$	$\pm 30$	$\pm 30$	V
Input voltage (see Notes 1 and 3)	$\pm 15$	$\pm 15$	$\pm 15$	V
Duration of output short circuit (see Note 4)	unlimited	unlimited	unlimited	
Continuous total dissipation			See Dissipation Rating Table	
Operating free-air temperature range	0 to 70	-40 to 85	-55 to 125	°C
Storage temperature range	-65 to 150	-65 to 150	-65 to 150	°C
Case temperature for 60 seconds	FK package		260	°C
Lead temperature 1.6 mm (1/16 inch) from case for 60 seconds	J or JG package		300	°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	D, N, P, or PW package	260	260	°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between  $V_{CC+}$  and  $V_{CC-}$ .  
 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.  
 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.  
 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

<b>PACKAGE</b>	<b><math>T_A \leq 25^\circ C</math> POWER RATING</b>	<b>DERATING FACTOR</b>	<b>DERATE ABOVE <math>T_A</math></b>	<b><math>T_A = 70^\circ C</math> POWER RATING</b>	<b><math>T_A = 85^\circ C</math> POWER RATING</b>	<b><math>T_A = 125^\circ C</math> POWER RATING</b>
D (8 Pin)	680 mW	5.8 mW/°C	32°C	464 mW	377 mW	N/A
D (14 Pin)	680 mW	7.6 mW/°C	60°C	608 mW	494 mW	N/A
FK	680 mW	11.0 mW/°C	88°C	680 mW	680 mW	275 mW
J	680 mW	11.0 mW/°C	88°C	680 mW	680 mW	275 mW
JG	680 mW	8.4 mW/°C	69°C	672 mW	546 mW	210 mW
N	680 mW	9.2 mW/°C	76°C	680 mW	598 mW	N/A
P	680 mW	8.0 mW/°C	65°C	640 mW	520 mW	N/A
PW (8 Pin)	525 mW	4.2 mW/°C	25°C	336 mW	N/A	N/A
PW (14 Pin)	700 mW	5.6 mW/°C	25°C	448 mW	N/A	N/A



**TEXAS  
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS  
77251-1443

**TL080, TL081, TL084, TL081A, TL082A, TL084A**  
**TL081B, TL082B, TL084B**  
**JFET-INPUT OPERATIONAL AMPLIFIERS**  
SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

**electrical characteristics,  $V_{CC\pm} = \pm 15$  V (unless otherwise noted)**

PARAMETER	TEST CONDITIONS†	TL080C			TL081AC			TL081BC			TL082I			TL084I			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_O = 0$ , $R_S = 50 \Omega$	TA = 25°C TA = full range	3	15	3	6	2	3	3	6	5	100	5	100	5	6	mV
$\alpha VIO$ Temperature coefficient of input offset voltage	$V_O = 0$ , TA = full range	$R_S = 50 \Omega$	18		18		18		18		5	100	5	100	5	9	µV/°C
$I_{IO}$ Input offset current‡	$V_O = 0$	TA = 25°C TA = full range	5	200	5	100	5	100	5	100	2	2	2	2	2	10	nA
$I_{IB}$ Input bias current‡	$V_O = 0$	TA = 25°C TA = full range	30	400	30	200	30	200	30	200	30	200	30	200	30	200	pA
$V_{ICR}$ Common-mode input voltage range	TA = 25°C		±11	-12	±11	-12	±11	-12	±11	-12	±11	-12	±11	-12	±11	20	nA
$V_{OM}$ Maximum peak output voltage swing	TA = 25°C	$R_L = 10 k\Omega$ $R_L \geq 10 k\Omega$	±12	±13.5	±12	±13.5	±12	±13.5	±12	±13.5	±12	±13.5	±12	±13.5	±12	±13.5	V
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 10$ V, TA = 25°C	$R_L \geq 2 k\Omega$	25	200	50	200	50	200	50	200	50	200	50	200	50	200	V/mV
$B_1$ Unity-gain bandwidth	$V_O = \pm 10$ V, TA = full range	$R_L \geq 2 k\Omega$	15		25		25		25		25		25		25		MHz
$r_i$ Input resistance	TA = 25°C		3		3		3		3		3		3		3		Ω
$CMRR$ Common-mode rejection ratio	$V_{IC} = V_{ICR}$ min, $V_O = 0$ , $R_S = 50 \Omega$ , TA = 25°C		10 <sup>12</sup>		10 <sup>12</sup>		10 <sup>12</sup>		10 <sup>12</sup>		10 <sup>12</sup>		10 <sup>12</sup>		10 <sup>12</sup>		dB
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{CC\pm} / \Delta V_{IO}$ )	$V_{CC} = \pm 15$ V to $\pm 9$ V, $V_O = 0$ , $R_S = 50 \Omega$ , TA = 25°C	70	86	80	86	80	86	80	86	80	86	80	86	80	86	80	dB
$I_{CC}$ Supply current (per amplifier)	No load, TA = 25°C	$V_O = 0$ ,	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	mA
$V_{O1}/V_{O2}$ Crosstalk attenuation	AVD = 100, TA = 25°C		120		120		120		120		120		120		120		dB

† All characteristics are measured under open-loop conditions with zero common-mode voltage unless otherwise specified. Full range for  $T_A$  is 0°C to 70°C for TL08<sub>+</sub> and 0°C to 85°C for TL08<sub>-</sub>.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 18. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

**TEXAS  
INSTRUMENTS**

POST OFFICE BOX 6643 • DALLAS, TEXAS 75265

# TL081M, TL082M, TL084M JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

## electrical characteristics, $V_{CC} \pm \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>T</sup>	TL081M, TL082M			TL084M			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$	Input offset voltage $V_O = 0, R_S = 50 \Omega$	$T_A = 25^\circ C$	3	6	3	9	mV	
			$T_A = -55^\circ C$ to $125^\circ C$	9		15		
$\alpha V_{IO}$	Temperature coefficient of input offset voltage $V_O = 0, R_S = 50 \Omega, T_A = -55^\circ C$ to $125^\circ C$			18		18		$\mu V/C$
$I_{IO}$	Input offset current <sup>F</sup> $V_O = 0$	$T_A = 25^\circ C$	5	100	5	100	pA	
		$T_A = 125^\circ C$		20		20	nA	
$I_{IB}$	Input bias current <sup>F</sup> $V_O = 0$	$T_A = 25^\circ C$	30	200	30	200	pA	
		$T_A = 125^\circ C$		50		50	nA	
$V_{ICR}$	Common-mode input voltage range $T_A = 25^\circ C$		$\pm 12$ to $\pm 11$ $\pm 15$		$\pm 12$ to $\pm 11$ $\pm 15$		V	
$V_{OM}$	Maximum peak output voltage swing $T_A = 25^\circ C, R_L = 10 k\Omega$	$\pm 12$	$\pm 13.5$	$\pm 12$	$\pm 13.5$			V
	$T_A = -55^\circ C$ to $125^\circ C, R_L \geq 10 k\Omega$	$\pm 12$		$\pm 12$		$\pm 12$		
	$T_A = -55^\circ C$ to $125^\circ C, R_L \geq 2 k\Omega$	$\pm 10$	$\pm 12$	$\pm 10$	$\pm 12$			
$A_{VD}$	Large-signal differential voltage amplification $V_O = \pm 10 V, T_A = 25^\circ C, R_L \geq 2 k\Omega$	25	200	25	200			V/mV
	$V_O = \pm 10 V, T_A = -55^\circ C$ to $125^\circ C, R_L \geq 2 k\Omega$	15		15				
$B_1$	Unity-gain bandwidth $T_A = 25^\circ C$		3		3		MHz	
$r_i$	Input resistance $T_A = 25^\circ C$		$10^{12}$		$10^{12}$		$\Omega$	
CMRR	Common-mode rejection ratio $V_{IC} = V_{ICR} \text{ min}, V_O = 0, R_S = 50 \Omega, T_A = 25^\circ C$	80	86	80	86		dB	
$k_{SVR}$	Supply voltage rejection ratio ( $\Delta V_{CC} \pm / \Delta V_{IO}$ ) $V_{CC} = \pm 15 V$ to $\pm 9 V, R_S = 50 \Omega, T_A = 25^\circ C$	80	86	80	86		dB	
$I_{CC}$	Supply current (per amplifier) No load, $V_O = 0, T_A = 25^\circ C$	1.4	2.8	1.4	2.8		mA	
$V_{O1}/V_{O2}$	Crosstalk attenuation $A_{VD} = 100, T_A = 25^\circ C$		120		120		dB	

<sup>T</sup> All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified.

<sup>F</sup> Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 18. Pulse techniques must be used that will maintain the junction temperatures as close to the ambient temperature as is possible.

## operating characteristics, $V_{CC} \pm \pm 15$ V, $T_A = 25^\circ C$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR Slew rate at unity gain	$V_I = 10 V, R_L = 2 k\Omega, C_L = 100 pF, \text{ See Figure 1}$	8*	13		V/ $\mu$ s
	$V_I = 10 V, R_L = 2 k\Omega, C_L = 100 pF, T_A = -55^\circ C$ to $125^\circ C, \text{ See Figure 1}$	5*			
$t_r$ Rise time	$V_I = 20 mV, R_L = 2 k\Omega, C_L = 100 pF, \text{ See Figure 1}$		0.05		$\mu$ s
	$C_L = 100 pF, \text{ See Figure 1}$		20%		
$V_n$ Equivalent input noise voltage	$R_S = 100 \Omega$	$f = 1 kHz$	18		nV/ $\sqrt{Hz}$
		$f = 10 Hz$ to $10 kHz$	4		
$I_n$ Equivalent input noise current	$R_S = 100 \Omega, f = 1 kHz$		0.01		$\mu A/\sqrt{Hz}$
THD Total harmonic distortion	$V_O(\text{rms}) = 10 V, R_S \leq 1 k\Omega, R_L \geq 2 k\Omega, f = 1 kHz$		0.003%		

\*On products compliant to MIL-STD-883, Class B, this parameter is not production tested.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS 77001

**TL080, TL081, TL084, TL081A, TL082A, TL084A  
TL081B, TL082B, TL084B  
JFET-INPUT OPERATIONAL AMPLIFIERS**  
SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

**TL082Y, TL084Y electrical characteristics,  $V_{CC\pm} = \pm 15$  V (unless otherwise noted)**

PARAMETER	TEST CONDITIONS <sup>†</sup>	MIN	TYP	MAX	UNIT
$V_{IO}$	$V_O = 0$ , $R_S = 50 \Omega$ , $T_A = 25^\circ C$		3	15	mV
$\alpha V_{IO}$	$V_O = 0$ , $R_S = 50 \Omega$ , $T_A = 25^\circ C$		18		$\mu V/^\circ C$
$I_{IO}$	$V_O = 0$ , $T_A = 25^\circ C$		5	200	pA
$I_{IB}$	$V_O = 0$ , $T_A = 25^\circ C$		30	400	pA
$V_{ICR}$	$T_A = 25^\circ C$	-12 $\pm 11$ to 15			V
$V_{OM}$	$T_A = 25^\circ C$ , $R_L = 10 k\Omega$	$\pm 12$	$\pm 13.5$		V
$A_{VD}$	$V_O = \pm 10$ V, $T_A = 25^\circ C$ , $R_L \geq 2 k\Omega$	25	200		V/mV
$B_1$	$T_A = 25^\circ C$		3		MHz
$r_i$	$T_A = 25^\circ C$		$10^{12}$		$\Omega$
CMRR	$V_{IC} = V_{ICR}$ min, $V_O = 0$ , $T_A = 25^\circ C$ , $R_S = 50 \Omega$	70	86		dB
$k_{SVR}$	$V_{CC} = \pm 15$ V to $\pm 9$ V, $V_O = 0$ , $R_S = 50 \Omega$ , $T_A = 25^\circ C$	70	86		dB
$I_{CC}$	No load, $V_O = 0$ , $T_A = 25^\circ C$		1.4	2.8	mA
$V_{O1}/V_{O2}$	$A_{VD} = 100$ , $T_A = 25^\circ C$		120		dB

<sup>†</sup> All characteristics are measured under open-loop conditions with zero common-mode voltage unless otherwise specified.

<sup>‡</sup> Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 18. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

**operating characteristics,  $V_{CC\pm} = \pm 15$  V,  $T_A = 25^\circ C$  (unless otherwise noted)**

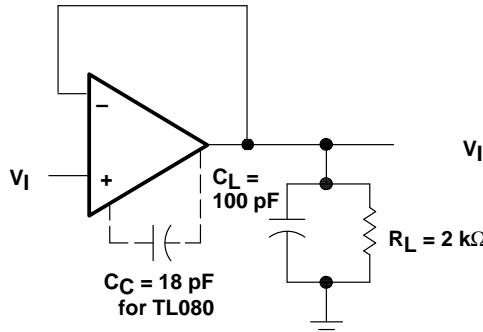
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	$V_I = 10$ V, $R_L = 2 k\Omega$ , $C_L = 100 \text{ pF}$ , See Figure 1	8	13		$V/\mu s$
$t_r$	$V_I = 20$ mV, $R_L = 2 k\Omega$ , $C_L = 100 \text{ pF}$ , See Figure 1		0.05		$\mu s$
Overshoot factor			20%		
$V_n$	$R_S = 100 \Omega$	f = 1 kHz	18		$nV/\sqrt{\text{Hz}}$
		f = 10 Hz to 10 kHz	4		$\mu V$
$I_n$	$R_S \leq 100 \Omega$ , f = 1 kHz		0.01		$pA/\sqrt{\text{Hz}}$
THD	$V_O(\text{rms}) = 10$ V, $R_S \leq 1 k\Omega$ , $R_L \geq 2 k\Omega$ , f = 1 kHz		0.003%		



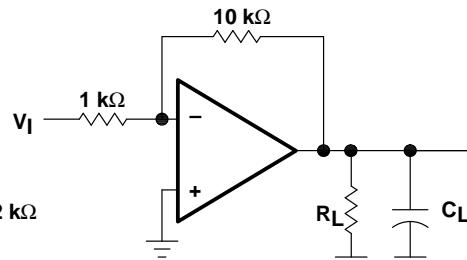
**TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A  
 TL081B, TL082B, TL084B, TL082Y, TL084Y  
 JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

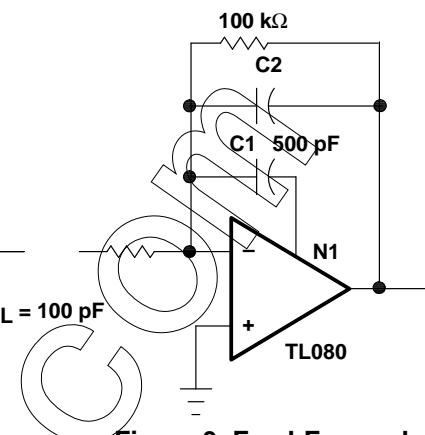
**PARAMETER MEASUREMENT INFORMATION**



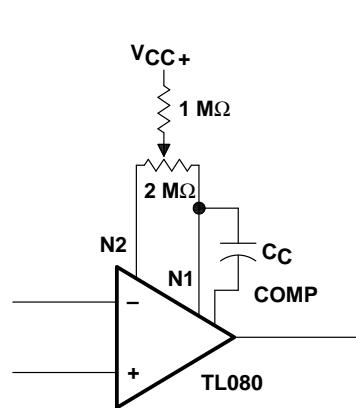
**Figure 1. Unity-Gain Amplifier**



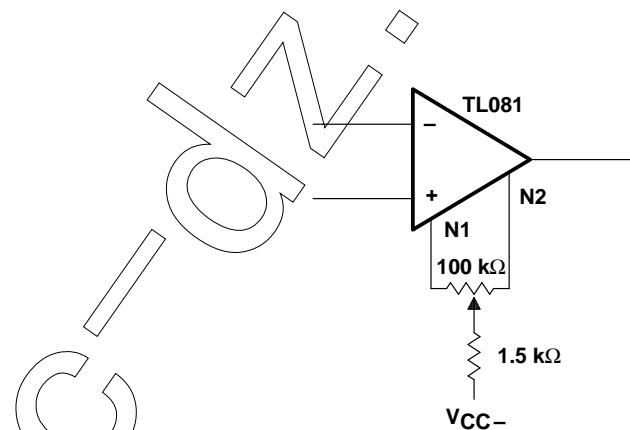
**Figure 2. Gain-of-10 Inverting Amplifier**



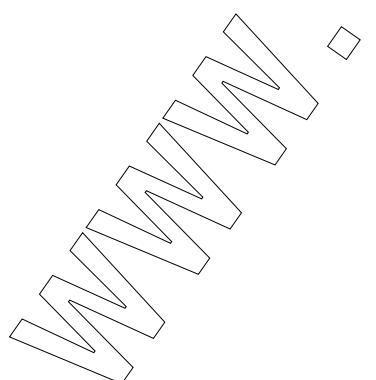
**Figure 3. Feed-Forward Compensation**



**Figure 4. TL080 Input Offset Voltage Null Circuit**



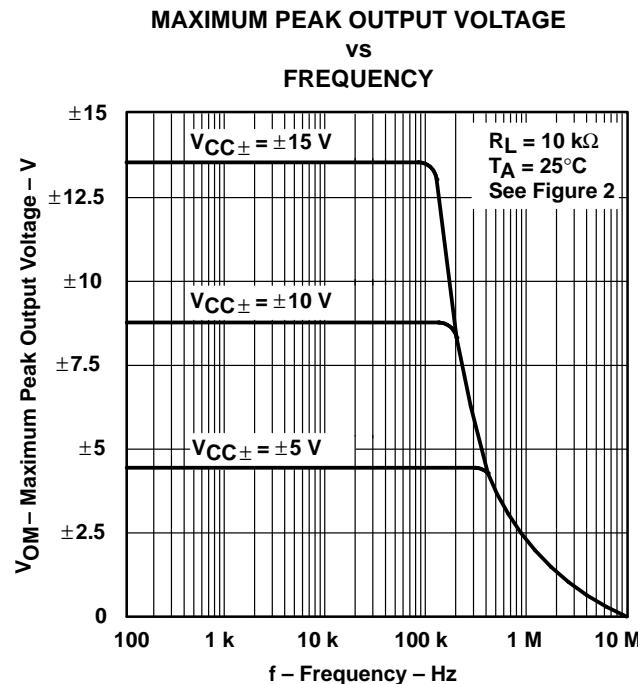
**Figure 5. TL081 Input Offset Voltage Null Circuit**



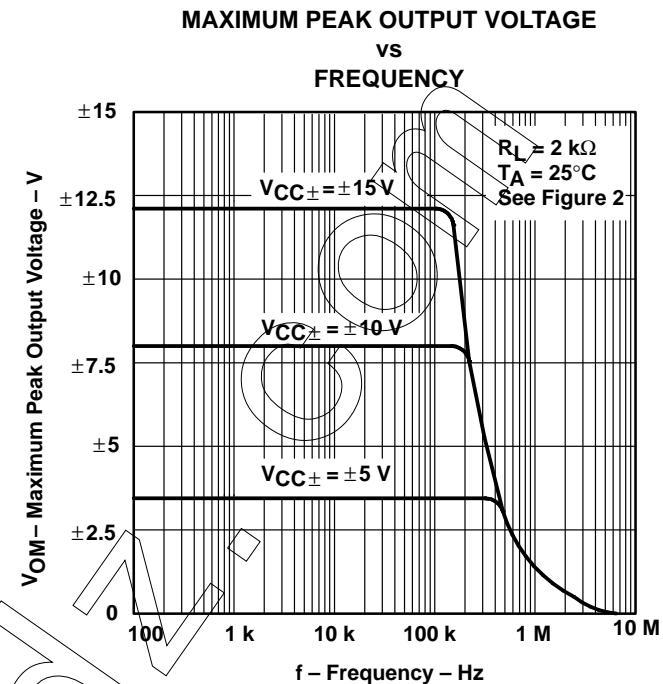
**TEXAS  
 INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
 POST OFFICE BOX 1443 • HOUSTON, TEXAS 77001

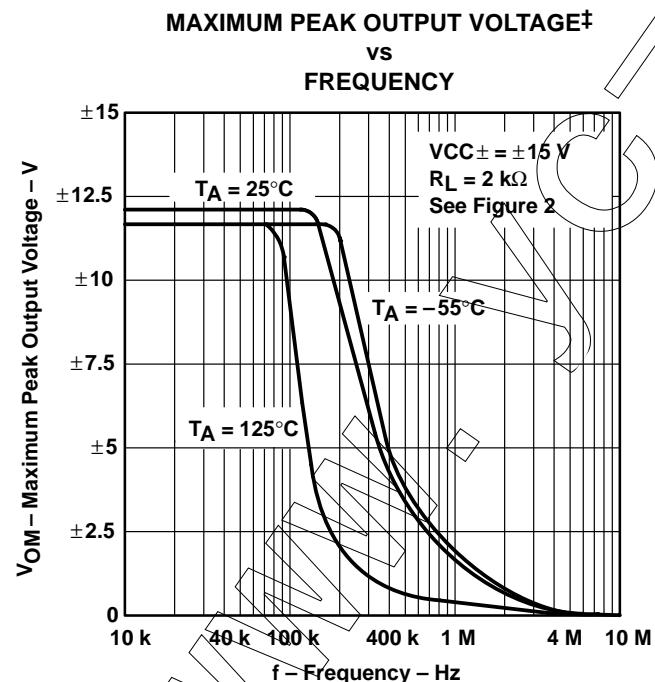
**TYPICAL CHARACTERISTICS<sup>†</sup>**



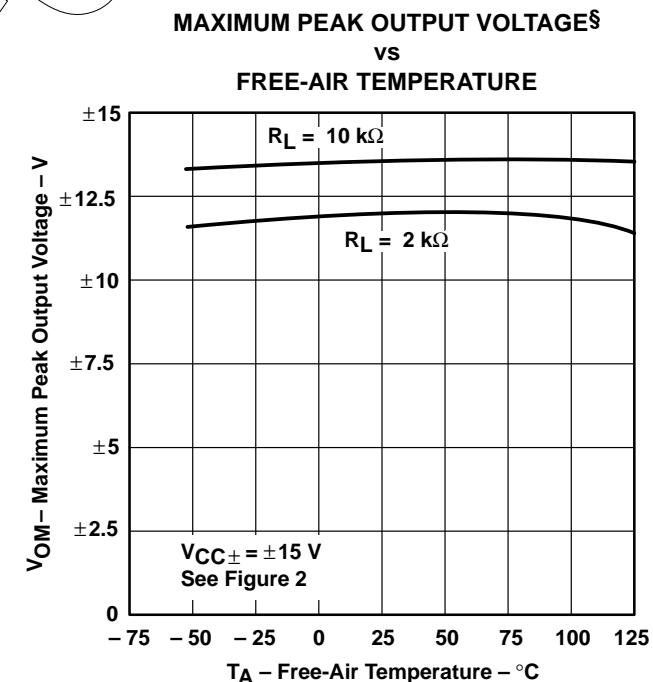
**Figure 6**



**Figure 7**



**Figure 8**



**Figure 9**

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. A 12-pF compensation capacitor is used with TL080.

<sup>‡</sup> The  $-55^\circ\text{C}$  curve and the  $125^\circ\text{C}$  curve apply only to the M version.

<sup>§</sup> The temperature range of the C version is  $0^\circ\text{C}$  to  $75^\circ\text{C}$ , the I version is  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ , and the M version is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ .

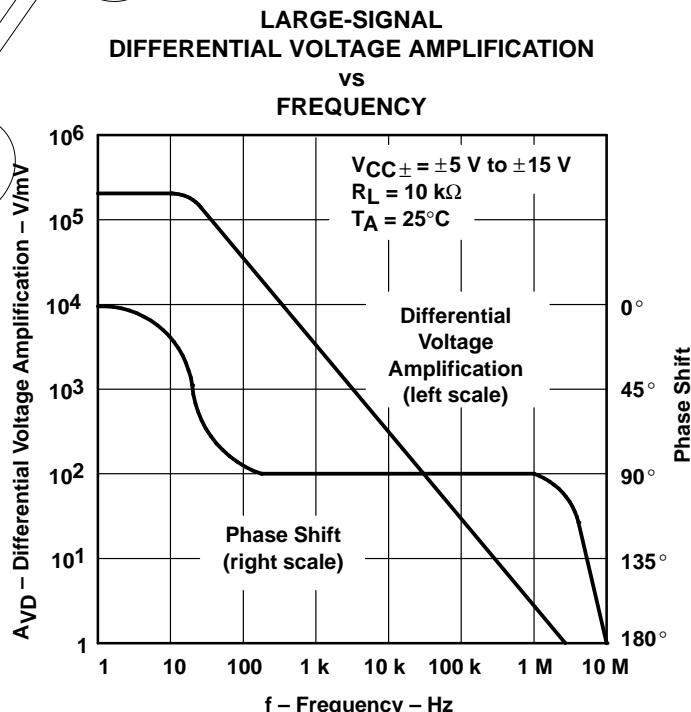
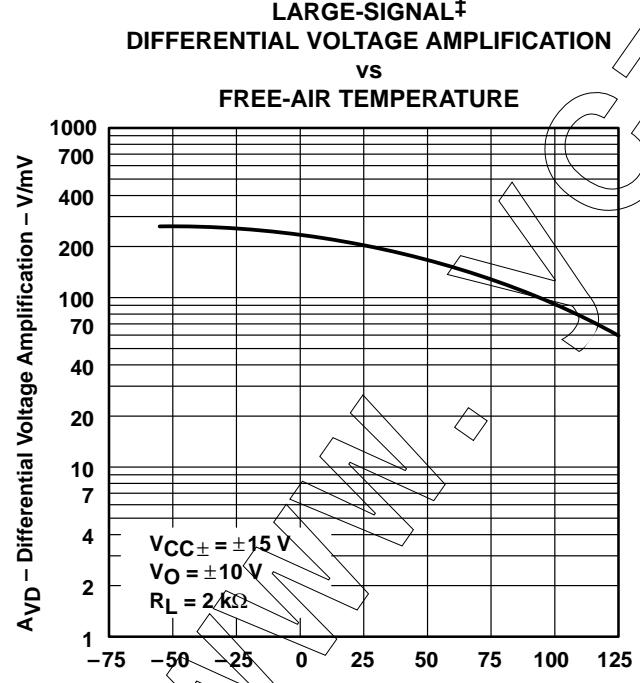
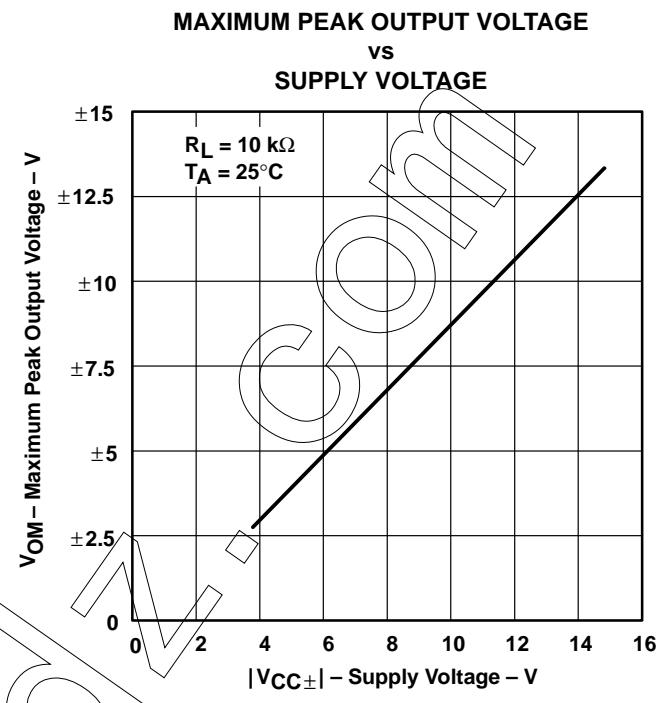
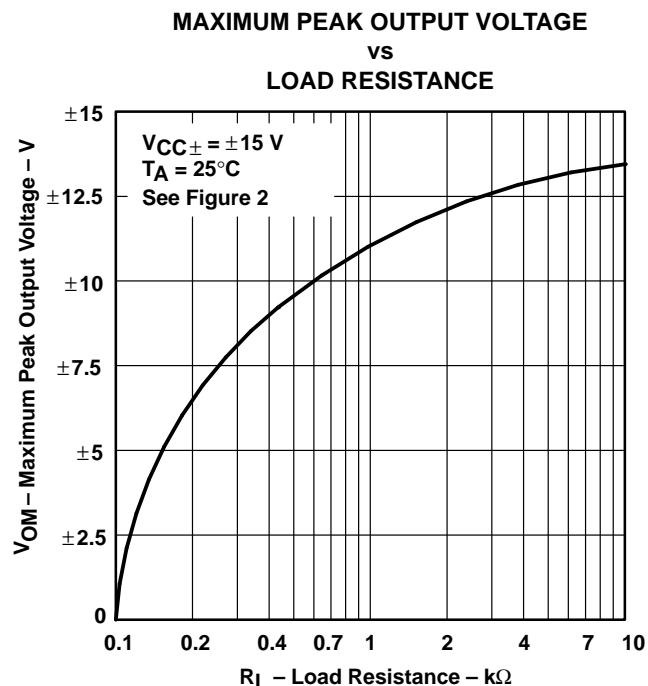
TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A

TL081B, TL082B, TL084B

## JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

### TYPICAL CHARACTERISTICS<sup>†</sup>



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. A 12-pF compensation capacitor is used with TL080.

<sup>‡</sup> The temperature range of the C version is 0°C to 75°C, the I version is -40°C to 85°C, and the M version is -55°C to 125°C.

**TYPICAL CHARACTERISTICS†**

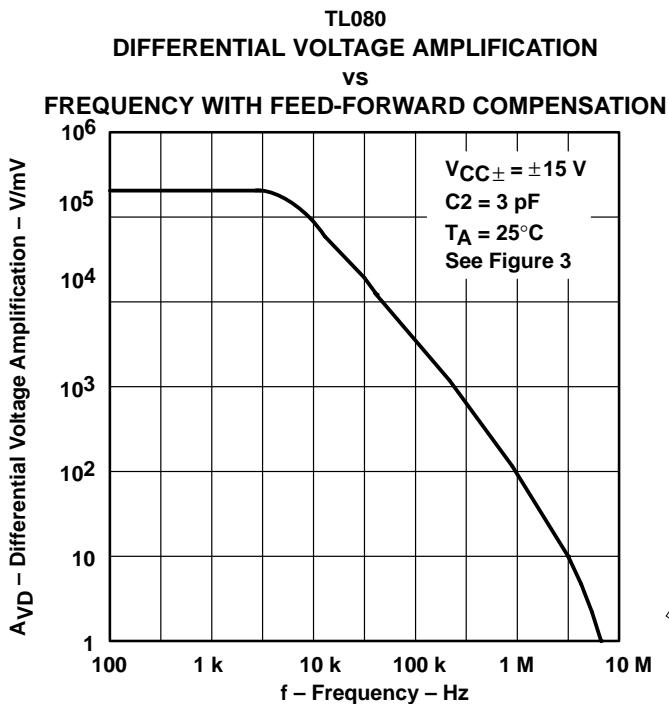


Figure 14

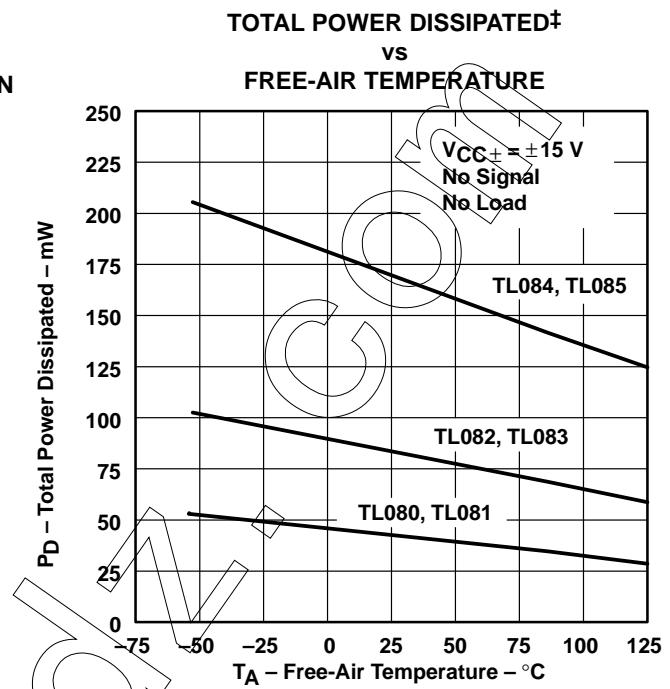


Figure 15

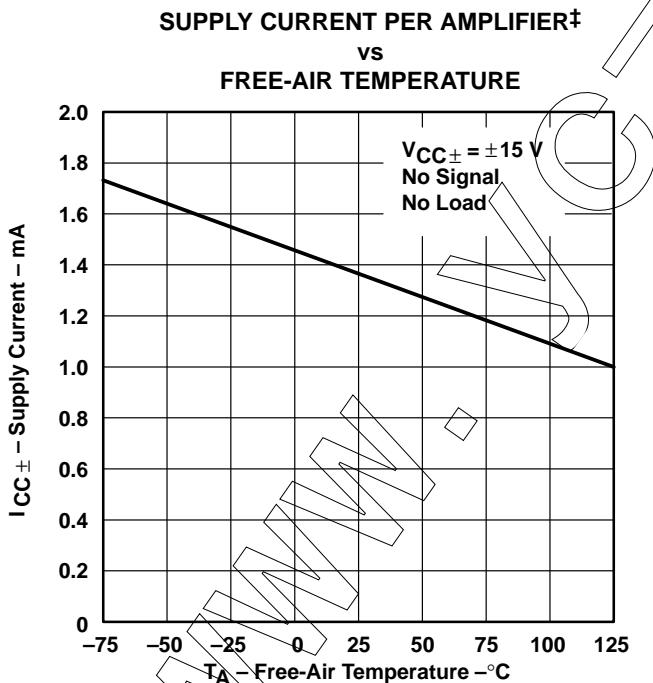


Figure 16

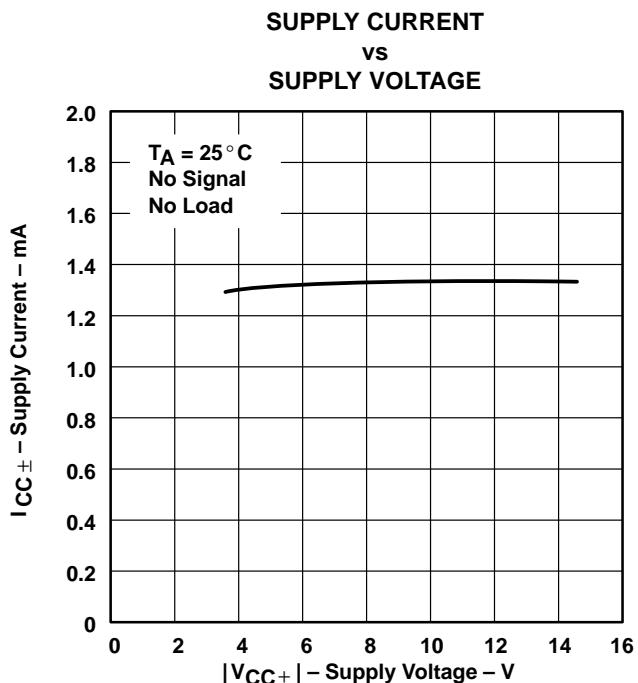


Figure 17

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. A 12-pF compensation capacitor is used with TL080.

‡ The temperature range of the C version is 0°C to 75°C, the I version is -40°C to 85°C, and the M version is -55°C to 125°C.

**TL080, TL081, TL082, TL084, TL081A, TL082A, TL084A  
TL081B, TL082B, TL084B**

**JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081A-D2297, FEBRUARY 1977-REVISED NOVEMBER 1992

**TYPICAL CHARACTERISTICS†**

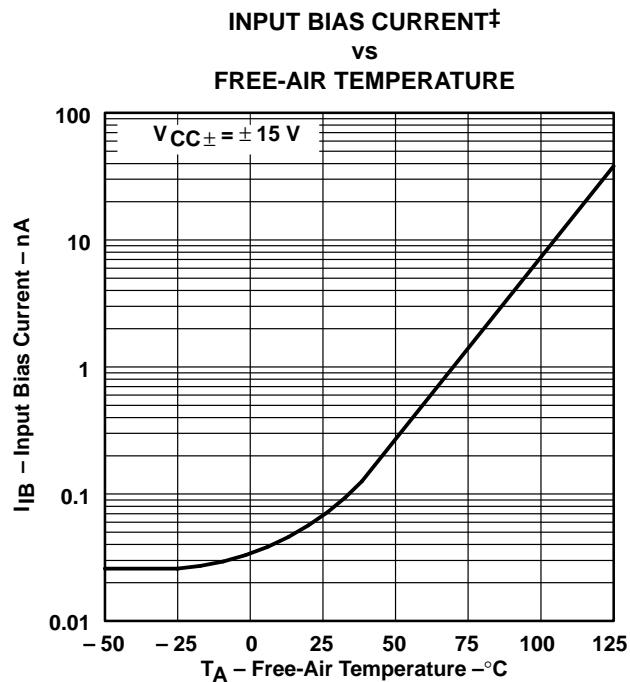


Figure 18

**VOLTAGE-FOLLOWER  
LARGE-SIGNAL PULSE RESPONSE**

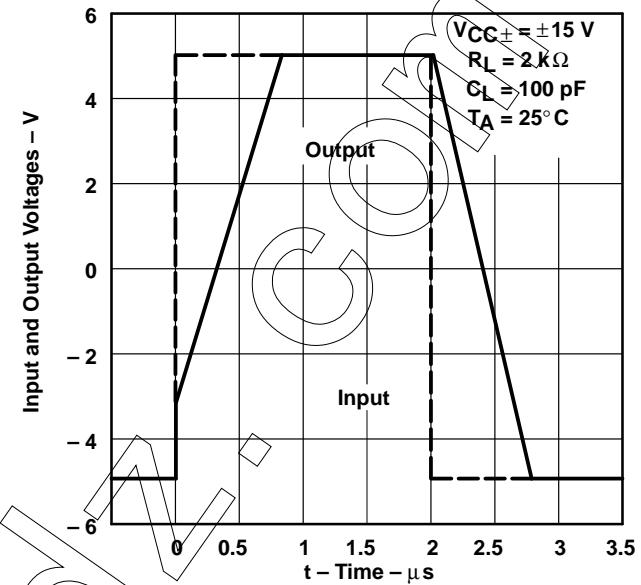


Figure 19

**OUTPUT VOLTAGE  
vs  
ELAPSED TIME**

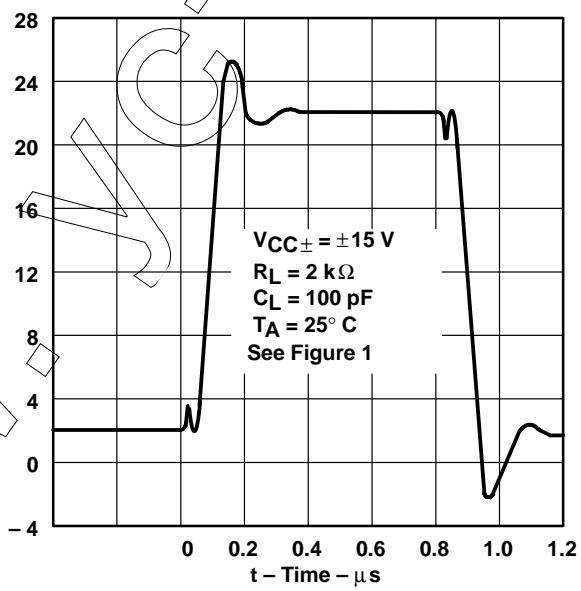


Figure 20

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. A 12-pF compensation capacitor is used with TL080.

‡ The temperature range of the C version is 0°C to 75°C, the I version is -40°C to 85°C, and the M version is -55°C to 125°C.

## TYPICAL CHARACTERISTICS†

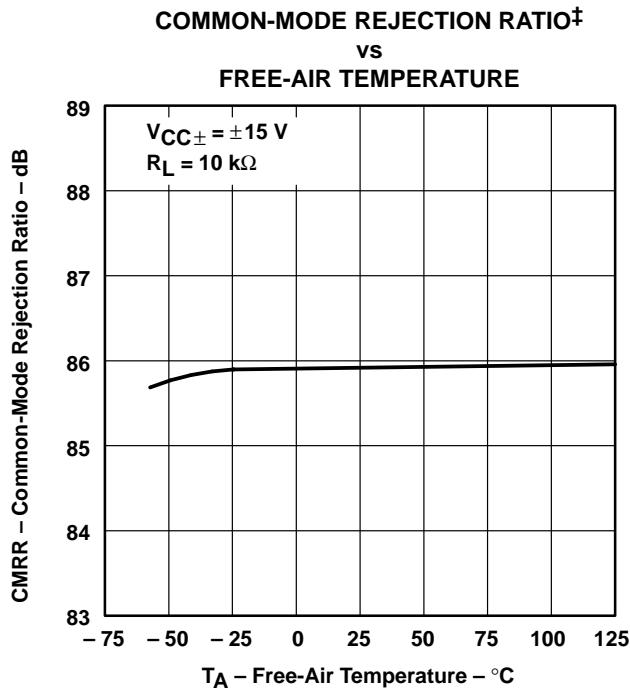


Figure 21

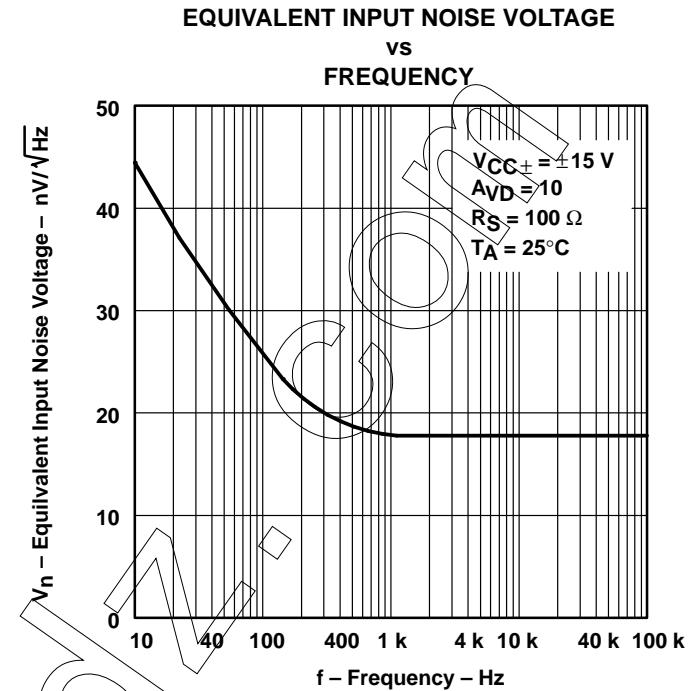


Figure 22

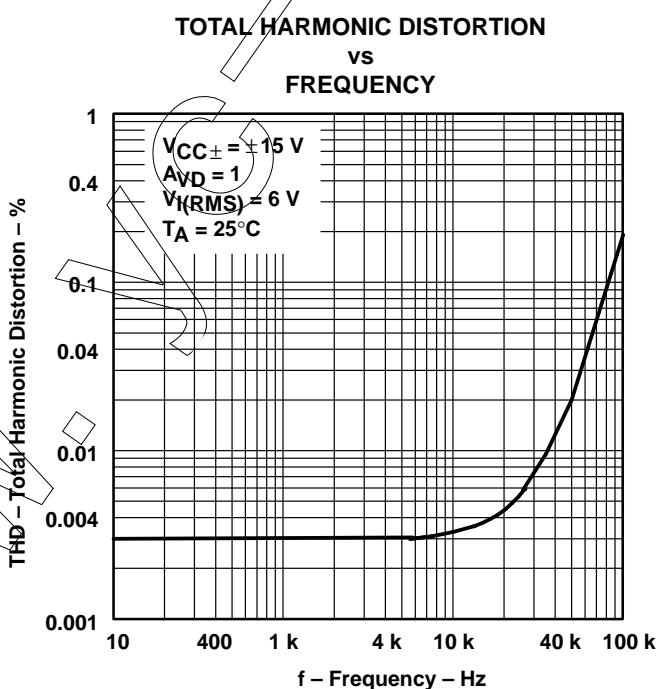


Figure 23

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. A 12-pF compensation capacitor is used with TL080.

‡ The temperature range of the C version is 0°C to 75°C, the I version is -40°C to 85°C, and the M version is -55°C to 125°C.

## TYPICAL APPLICATION DATA

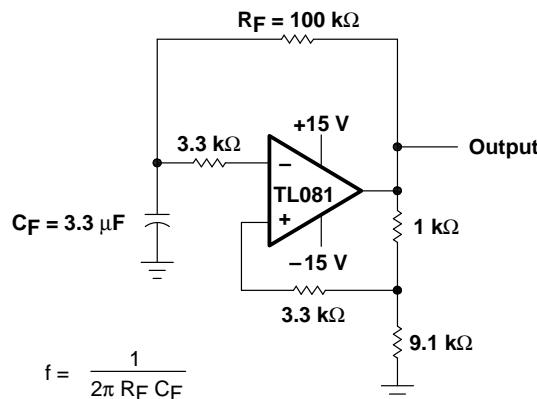


Figure 24. 0.5-Hz Square-Wave Oscillator

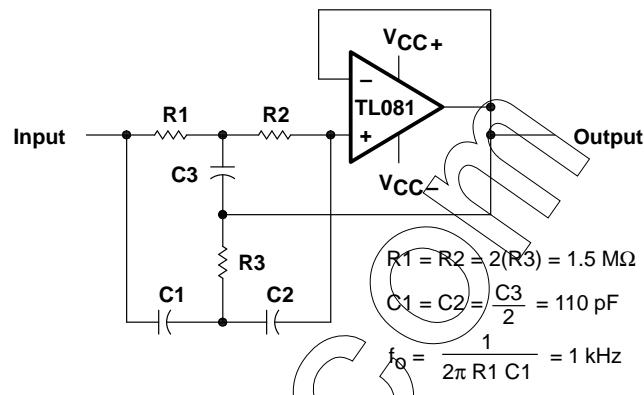


Figure 25. High-Q Notch Filter

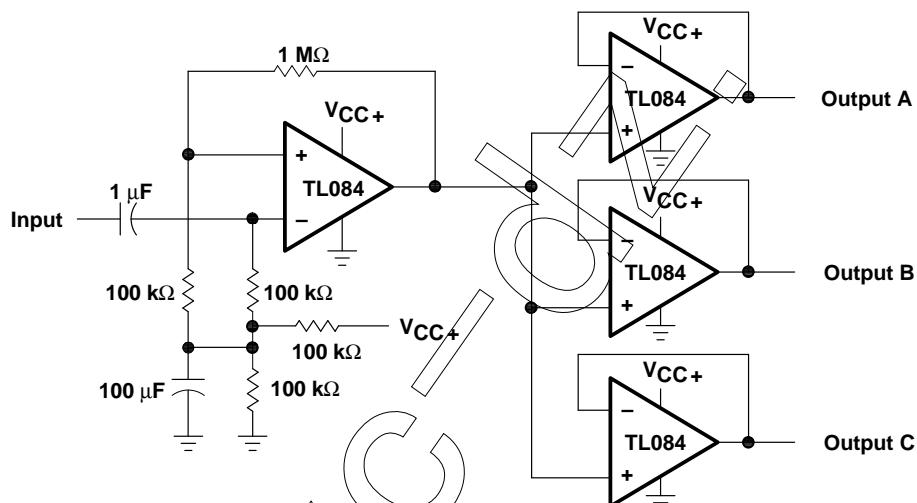
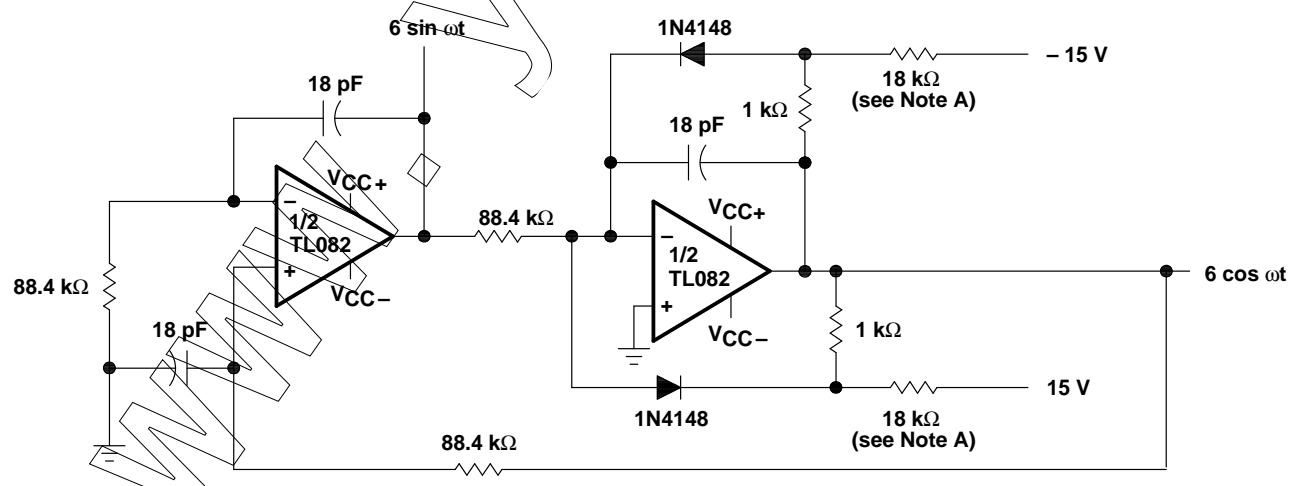


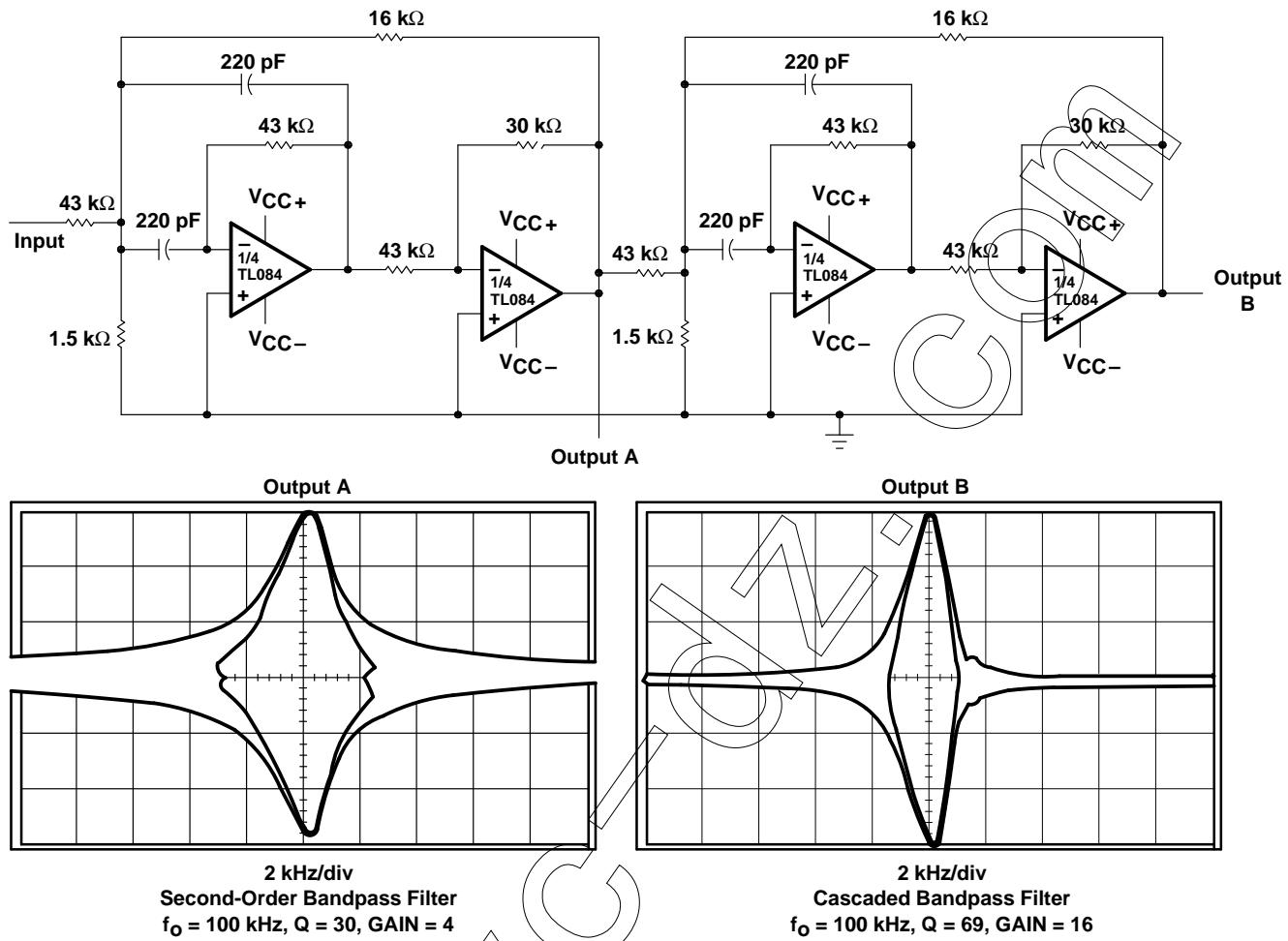
Figure 26. Audio Distribution Amplifier



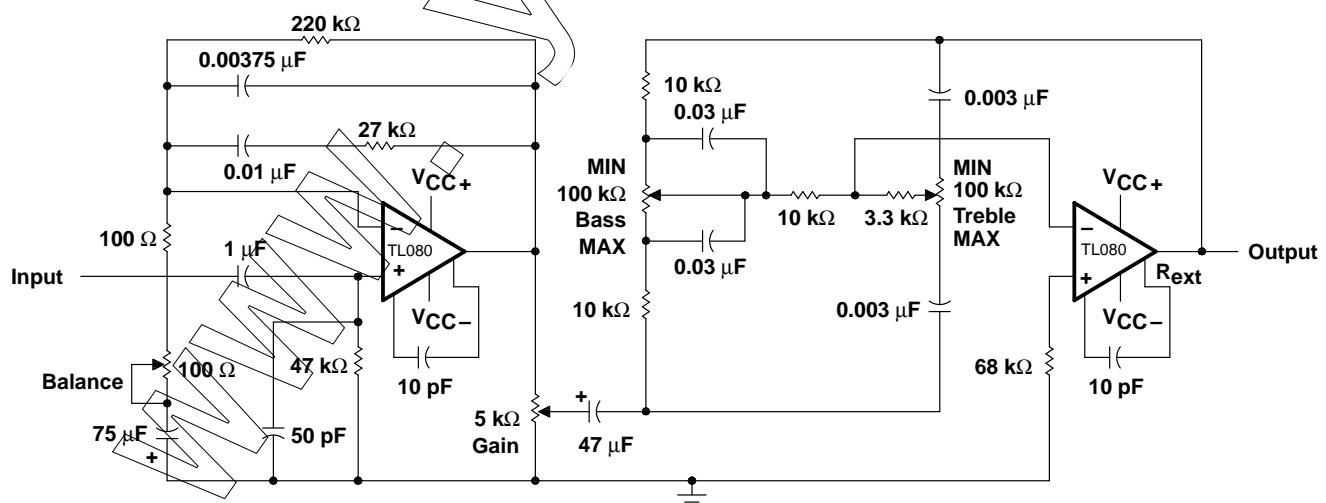
NOTE A: These resistor values may be adjusted for a symmetrical output.

Figure 27. 100-KHz Quadrature Oscillator

**TYPICAL APPLICATION DATA**



**Figure 28. Positive-Feedback Bandpass Filter**



**Figure 29. IC Preamplifier**

com

www.ycz.com

www.ycz.com

## **IMPORTANT NOTICE**

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

**TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.**

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1995, Texas Instruments Incorporated